EECS 217

Lecture 1: Introduction to Microwave Circuits

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What Are Microwave Circuits?

- First we must understand where circuit theory comesfrom. Crudely speaking, circuit theory is an approximation to Maxwell's Eq. valid when structure dimensions are small relative to the wavelength (at thehighest frequency of interest).
- Alternatively, circuit theory is valid when the speed of light is infinite $c\to\infty.$
- Ex: At $f=60\,{\rm{Hz}},$ we have $\lambda=\frac{c}{f}$ If we arbitrarily require that the dimension be ^a factor of $\frac{c}{f}=\frac{3}{2}$ $\times 10$ 8 $\frac{1}{60}$ $\frac{10^{\circ}}{0} = 0.5 \times 10^{7}$ ^a thousand smaller than the wavelength, we have

$$
\frac{\ell}{\lambda} = 10^{-3} \rightarrow \ell = 5 \,\mathrm{km}
$$

Circuits at GHz Frequencies

Now let's consider $f = 1 \, \mathrm{GHz}$. This corresponds to the popular cellular bands. Now $\lambda=c/f=30\,\mathrm{cm},$ so usin the same requirement we have $\epsilon = c/f = 30 \, \mathrm{cm}$, so using

$$
\frac{\ell}{\lambda} = 10^{-3} \rightarrow \ell = 0.3 \,\text{mm}
$$

- This is ^a lot more restrictive! We see that this is strictly only valid for relatively small structures on the Si chip. So inside ^a small transistor with ^a dimension of tens of microns, certainly circuit theory is valid at thisfrequency.
- But recall that $\lambda=$ substrate the wavelength for TEM waves drops by $= v/f$ = $c/\sqrt{\epsilon\mu}f,$ so inside the Si roughtly $\sqrt{12}.$

Microwave Circuit Theory

- **Microwave circuit theory is an extension of circuit theory** to higher frequencies where the circuit dimensionsapproach the wavelength, $\ell \sim \lambda$.
- We need this theory in order to avoid solving Maxwell'sEquations!
- We can also use our intuition and experience fromcircuit theory (e.g. lumped filter design) and apply it to higher frequencies. We have to be careful in applyingour inuition.
- For instance, a transmission line of lenght $\lambda/4$ converts an open circuit termination into ^a short circuit! This behavior is very counterintuitive from ^a lumped circuit theory perspective.

Chip/Package/Board

I In the above example, the structures "on-chip" may behave like lumped elements (transistors, inductors, capacitors, etc.). The leads, board traces, and radiation structures, though, are "large" relative to the wavelengthand require Microwave Theory.

Microwave Radar

- Radar, invented by Sir Robert Watson-Watt in 1935, and developed at MRL during WWII ('40 - '45), allows us to detect distant objects by observing the microwavescattering from ^a target.
- **In this course we'll learn to build the basic active and** passive building blocks, such as the oscillators, amplifiers, mixers, and circulator.

Radio Block Diagram

• The block diagram above is a typical super-heterodyne transceiver architecture. The LNA (low-noise amplifier), the PA (power amplifier), the LO (local oscillator), andmixers all operate at the "carrier" frequency. We will learn how to design such building blocks operatingclose to the limits of technology $(10\,\mathrm{GHz}-100's\,\mathrm{G})$ $-100's\,\mathrm{GHz}$).

Maxwell's Equations

We begin with Maxwell's famous equations:

$$
\oint_{S} \mathbf{D} \cdot d\mathbf{S} = \int_{V} \rho dV \qquad \nabla \cdot \mathbf{D} = \rho
$$
\n
$$
\oint_{C} \mathbf{B} \cdot d\mathbf{S} = 0 \qquad \nabla \cdot \mathbf{B} = 0
$$
\n
$$
\oint_{C} \mathbf{E} \cdot d\ell = -\frac{\partial}{\partial t} \int_{S} \mathbf{B} \cdot d\mathbf{S} \qquad \nabla \times \mathbf{E} = -\frac{\partial \mathbf{B}}{\partial t}
$$

$$
\oint_C \mathbf{H} \cdot d\ell = \frac{\partial}{\partial t} \int_S \mathbf{D} \cdot d\mathbf{S} + \int_S \mathbf{J} \cdot d\mathbf{S} \qquad \nabla \times \mathbf{H} =
$$

 ∂ ${\bf D}$

 ∂t

 $+\,{\bf J}$

Maxwell's Eq. (cont)

- EElectric Field
- H Magnetic Field
- D **Electric Flux Density**
- BMagnetic Flux Density

$$
[E] = \frac{V}{m}
$$

\n
$$
[H] = \frac{A}{m}
$$

\n
$$
[D] = \frac{C}{m^2}
$$

\n
$$
[B] = \frac{\text{Weber}}{m^2} = T = \frac{V \cdot s}{m^2}
$$

- It's important to note that these equations follow from experimental observations:
- Gauss' Law (equivalent to Coulomb Force equation)from the inverse square law. Also, no magneticmonopoles have ever been observed.
- Faraday's law of electromagnetic induction. Ampere's law in addition to displacement current for consistency(equivalently charge conservation).

Constitutive Relations

Force Law: For a charge q moving at velocity ${\bf v}$ through an electromagnetic field, the forice experienced by thecharge is given by

$$
\mathbf{f} = q(\mathbf{E} + \mathbf{v} \times \mathbf{B})
$$

Ohm's Law: <code>For</code> a conductor with conductivity σ *(S/m),* the current density ${\rm J}$ is given by

$$
\mathbf{J}=\sigma\mathbf{E}
$$

- In this class σ is a scalar so the current is in the direction of the field ${\rm E.}$
- *Convection Current:* For a charge density ρ moving with velocity $\rm{v_{p},}$ the current density is

Permittivity (Dielectric Constant)

The electric flux density D is related to the electric field
intensity E by intensity $\boldsymbol{\mathrm{E}}$ by

 $\mathbf{D}=\epsilon\mathbf{E}=\epsilon_r\epsilon_0\mathbf{E}$ $\epsilon_0 \approx 8.854 \times 10^{-12}$ 2 F/m

- The relative permittivity ϵ_r atomic and molecular dipoles in the material. For most $_r$ characterizes the effect of the microwave materials we assume ϵ is a scalar constant. Most problems are characterized by homogeneous, isotropic, linear, time-invariant materials.
- The frequency response of ϵ is very important as the imaginary component of ϵ gives rise to loss at microwave frequencies.

Permeability

The magnetic flux density B is related to the magnetic
field II by field $\boldsymbol{\mathrm{H}}$ by

 $\mathbf{B}=\mu\mathbf{H}=\mu_{r}\mu_{0}\mathbf{H}$ μ_0 $_0 = 4\pi \times 10^{-7}$ $\frac{1}{\text{H}}$

- The relative permeability μ_r constituent atomic and/or molecular magnetic dipole $_r$ measures the effect of moments.
- Most materials in nature are diamagnetic. The induced magnetic fields *oppose* the applied field. But the response is usually very weak and so $\mu\sim$ rnn n ¹. This is dueprimarily to the response of the electron "orbit" in anatom.

Paramegnetic Materials

- Some materials have a natural net magnetic dipole moment. Such materials give ^a paramagnetic responsewhich can arise from dipole moments in an atom, molecules, crystal defects, and conduction electrons. The dipole moments tend to align with the magnetic field but are deflected from complete alignment by theirthermal activity.
- The fields resulting from the partial alignment *adds* to the applied field so $\mu\geq1.$ It can be shown that this 11 1A IV effect is also relatively weak so that at roomtemperature $\mu \approx 1 + 10^{-5}$

Materials with residual magnetization exist where it is energetically favorable for internal magnetic dipoles toalign spontaneously below ^a certain (Curie)temperature. These ferromagnetic and ferrimagnetic materials exhibit non-linear and large μ factors $\sim 10^3$ – -10^6 .

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Displacement Current

Ampere discovered that the magnetic field in staticsitutations can be calcuated by $\nabla \times \mathbf{H} = \mathbf{J}$. Equiva ^J. Equivalently,

$$
\int_{S} \nabla \times \mathbf{H} \cdot d\mathbf{S} = \oint_{C} \mathbf{H} \cdot d\ell = \int_{S} \mathbf{J} \cdot d\mathbf{S} = I
$$

- The above equation is a mathematical identity for *any* surface bounded by the contour $C.$ Now Maxwell realized ^a flaw in this equation when you consider anAC current and ^a capacitor.
- Since $\mathbf{J}\equiv0$ on surface S_2 , but $\mathbf{J}\neq0$ for surface S_1 , this leads to ^a contradiction. (see next page)

Displacement Current (cont)

• To resolve this, Maxwell introduced ^a displacement current to Ampere's eq.

 $\nabla \times \mathbf{H} = \mathbf{J} + \mathbf{J_d}$

Furthermore, since $\nabla \cdot \nabla \times {\bf A} \equiv 0$, this implies that $\nabla \cdot \mathbf{J}=0$, violating charge conservation, unless we
introduce I . Moxivell defined introduce J_d . Maxwell defined

$$
\mathbf{J_d} = \frac{\partial \mathbf{D}}{\partial t}
$$

to account for charge conservation since $\nabla \cdot \mathbf{D} = \rho$.
This means that meanstip fields san he generated l This means that magnetic fields can be generated bycurrents or by changing electric fields.

Radiation and EM Propagation

The introduction of displacement current allows EMwaves. To see this intuitively, note that in ^a charge-freeregion of space

$$
\nabla \times \mathbf{E} = -\frac{\partial \mathbf{B}}{\partial t}
$$

$$
\nabla \times \mathbf{B} = \mu \epsilon \frac{\partial \mathbf{E}}{\partial t}
$$

This exchange happens at the speed of light.

Wave Equation in 3D

• We can derive the wave equation directly in a coordinate free manner using vector analysis

$$
\nabla \times \nabla \times \mathbf{E} = \nabla \times -\mu \frac{\partial \mathbf{H}}{\partial \mathbf{t}} = \mu \frac{\partial (\nabla \times \mathbf{H})}{\partial t}
$$

Substitution from Maxwell's eq.

$$
\nabla \times \mathbf{H} = \frac{\partial \mathbf{D}}{\partial t} = \epsilon \frac{\partial \mathbf{E}}{\partial t}
$$

$$
\nabla \times \nabla \times \mathbf{E} = -\mu \epsilon \frac{\partial^2 E}{\partial t^2}
$$

Wave Eq. in 3D (cont)

- Using the identity $\nabla \times \nabla \times {\bf E} = \nabla^2$ $^{\mathbf{2}}\mathbf{E}+\nabla\left(\nabla\cdot\mathbf{E}\right)$
- Since $\nabla \cdot \textbf{E}=0$ in charge free regions

$$
\nabla^2 \mathbf{E} = \mu \epsilon \frac{\partial^2 \mathbf{E}}{\partial t^2}
$$

In Phasor form we have k^2 $^2=\omega^2\mu\epsilon$

$$
\nabla^{\mathbf{2}}\mathbf{E}=-k^2\mathbf{E}
$$

• Now it's trivial to get a 1-D version of this equation

$$
\nabla^2 E_x = \mu \epsilon \frac{\partial^2 E_x}{\partial t^2} \qquad \frac{\partial^2 E_x}{\partial x^2} = \mu \epsilon \frac{\partial^2 E_x}{\partial t^2}
$$